

ST1000C..K SERIES

PHASE CONTROL THYRISTORS

Hockey Puk Version

Features

- Center amplifying gate
- Metal case with ceramic insulator
- International standard case A-24 (K-PUK)
- High profile hockey-puk

1473A

Typical Applications

- DC motor controls
- Controlled DC power supplies
- AC controllers

case style A-24 (K-PUK)

Major Ratings and Characteristics

| Parameters | ST1000C..K | Units |
|-------------------------|--------------|--------------------|
| $I_{T(AV)}$ | 1473 | A |
| @ T_{hs} | 55 | °C |
| $I_{T(RMS)}$ | 2913 | A |
| @ T_{hs} | 25 | °C |
| I_{TSM} | 20.0 | KA |
| @ 50Hz | 21.2 | KA |
| I^2t | 2000 | KA ² s |
| @ 60Hz | 1865 | KA ² s |
| $I^2\sqrt{t}$ | 20000 | KA ² /s |
| V_{DRM}/V_{RRM} range | 1200 to 2600 | V |
| t_q | typical | 300 |
| | range | μs |
| T_J | range | -40 to 125 |
| | | °C |

ST1000C..K Series

Bulletin I25202 rev. A 01/00

International
IR Rectifier

ELECTRICAL SPECIFICATIONS

Voltage Ratings

| Type number | Voltage Code | V_{RRM} , maximum repetitive peak reverse voltage V | V_{RSM} , maximum non-repetitive peak rev. voltage V | I_{RRM} max. @ $T_J = 125^\circ C$ mA |
|-------------|--------------|---|--|---|
| ST1000C..K | 12 | 1200 | 1300 | 100 |
| | 16 | 1600 | 1700 | |
| | 20 | 2000 | 2100 | |
| | 22 | 2200 | 2300 | |
| | 24 | 2400 | 2500 | |
| | 26 | 2600 | 2700 | |

On-state Conduction

| Parameter | ST1000C..K | Units | Conditions | | | |
|---------------|---|----------------------------|---|--|--|--|
| $I_{T(AV)}$ | Maximum average on-state current @ Heatsink temperature | A | 180° conduction, half sine wave | $^{\circ}C$ | Double side (single side) cooled | |
| | 55 (85) | $^{\circ}C$ | | | | |
| $I_{T(RMS)}$ | Maximum RMS on-state current | A | DC @ 25°C heatsink temp. double side cooled | | | |
| I_{TSM} | Maximum peak, one-cycle, non-repetitive surge current | KA | $t = 10ms$ | No voltage reapplied | Sinusoidal half wave, Initial $T_J = T_J$ max. | |
| | 20.0 | | $t = 8.3ms$ | | | |
| | 21.2 | | $t = 10ms$ | 100% V_{RRM} | | |
| | 17.0 | | $t = 8.3ms$ | reapplied | | |
| I^2t | Maximum I^2t for fusing | KA ² s | $t = 10ms$ | No voltage reapplied | | |
| | 2000 | | $t = 8.3ms$ | | | |
| | 1865 | | $t = 10ms$ | 100% V_{RRM} | | |
| | 1445 | | $t = 8.3ms$ | reapplied | | |
| $I^2\sqrt{t}$ | Maximum $I^2\sqrt{t}$ for fusing | KA ² \sqrt{s} | $t = 0.1$ to 10ms, no voltage reapplied | | | |
| | 20000 | | | | | |
| | 1360 | | | | | |
| | 1865 | | | | | |
| $V_{T(TO)1}$ | Low level value of threshold voltage | 0.950 | V | $(16.7\% \times \pi \times I_{T(AV)} < I < \pi \times I_{T(AV)})$, $T_J = T_J$ max. | | |
| $V_{T(TO)2}$ | High level value of threshold voltage | 1.024 | | $(I > \pi \times I_{T(AV)})$, $T_J = T_J$ max. | | |
| r_{t1} | Low level value of on-state slope resistance | 0.283 | mΩ | $(16.7\% \times \pi \times I_{T(AV)} < I < \pi \times I_{T(AV)})$, $T_J = T_J$ max. | | |
| r_{t2} | High level value of on-state slope resistance | 0.265 | | $(I > \pi \times I_{T(AV)})$, $T_J = T_J$ max. | | |
| V_{TM} | Maximum on-state voltage drop | 1.80 | V | $I_{pk} = 3000A$, $T_J = 125^\circ C$, $t_p = 10ms$ sine pulse | | |
| I_H | Maximum holding current | 600 | | | | |
| I_L | Typical latching current | 1000 | mA | $T_J = 25^\circ C$, anode supply 12V resistive load | | |

Switching

| Parameter | ST1000C..K | Units | Conditions |
|--|------------|-------|---|
| di/dt Maximum non repetitive rate of rise of turned-on current | 1000 | A/μs | Gate drive 20V, 20Ω, $t_g \leq 1\mu s$ $T_J = T_{J_{max.}}$, anode voltage $\leq 80\%$ V_{DRM} |
| t_d Typical delay time | 1.9 | μs | Gate current 1A, $di_g/dt = 1A/\mu s$ $V_d = 0.67\% V_{DRM}$, $T_J = 25^\circ C$ |
| t_q Typical turn-off time | 300 | A/μs | $I_{TM} = 550A$, $T_J = T_{J_{max.}}$, di/dt = 40A/μs, $V_R = 50V$ $dv/dt = 20V/\mu s$, Gate 0V 100Ω, $t_p \leq 500\mu s$ |

Blocking

| Parameter | ST1000C..K | Units | Conditions |
|--|------------|-------|--|
| dv/dt Maximum critical rate of rise of off-state voltage | 500 | V/μs | $T_J = T_{J_{max.}}$, linear to 80% rated V_{DRM} |
| I_{RRM} Maximum peak reverse and off-state leakage current | 100 | μs | $T_J = T_{J_{max.}}$, rated V_{DRM}/V_{RRM} applied |

Triggering

| Parameter | ST1000C..K | Units | Conditions |
|---|--------------------------|-----------------------|---|
| P_{GM} Maximum peak gate power | 16 | W | $T_J = T_{J_{max.}}$, $t_p \leq 5ms$ |
| $P_{G(AV)}$ Maximum peak average gate power | 3 | W | $T_J = T_{J_{max.}}$, $f = 50Hz$, $d\% = 50$ |
| I_{GM} Maximum peak positive gate current | 3.0 | A | $T_J = T_{J_{max.}}$, $t_p \leq 5ms$ |
| + V_{GM} Maximum peak positive gate voltage | 20 | V | |
| - V_{GM} Maximum peak negative gate voltage | 5.0 | V | |
| I_{GT} DC gate current required to trigger | TYP. 200 100 50 | MAX. - 200 - | $T_J = -40^\circ C$ $T_J = 25^\circ C$ $T_J = 125^\circ C$ Max. required gate trigger / current / voltage are the lowest value which will trigger all units 12V anode-to-cathode applied |
| V_{GT} DC gate voltage required to trigger | 1.4 1.1 0.9 | - 3.0 - | $T_J = -40^\circ C$ $T_J = 25^\circ C$ $T_J = 125^\circ C$ T _J = 125°C |
| I_{GD} DC gate current not to trigger | 10 | mA | $T_J = T_{J_{max.}}$ Max. gate current / voltage not to trigger is the max. value which will not trigger any units with rated V_{DRM} anode-to-cathode applied |
| V_{GD} DC gate voltage not to trigger | 0.25 | V | |

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Thermal and Mechanical Specifications

| Parameter | ST1000C..K | Units | Conditions | |
|---------------------|---|-------------------|------------|---------------------------------|
| T _J | Max. junction operating temperature range | -40 to 125 | °C | |
| T _{stg} | Max. storage temperature range | -40 to 150 | | |
| R _{thJ-hs} | Max. thermal resistance, junction to heatsink | 0.042 | K/W | DC operation single side cooled |
| | | 0.021 | | DC operation double side cooled |
| R _{thC-hs} | Max. thermal resistance, case to heatsink | 0.006 | K/W | DC operation single side cooled |
| | | 0.003 | | DC operation double side cooled |
| F | Mounting force, ± 10% | 24500 (2500) | N (Kg) | |
| wt | Approximate weight | 425 | g | |
| Case style | A-24 (K-PUK) | See outline table | | |

ΔR_{thJC} Conduction

(The following table shows the increment of thermal resistance R_{thJC} when devices operate at different conduction angles than DC)

| Conduction angle | Sinusoidal conduction | | Rectangular conduction | | Units | Conditions |
|------------------|-----------------------|-------------|------------------------|-------------|-------|--------------------------------------|
| | Single Side | Double Side | Single Side | Double Side | | |
| 180° | 0.003 | 0.003 | 0.002 | 0.002 | K/W | T _J = T _J max. |
| 120° | 0.004 | 0.004 | 0.004 | 0.004 | | |
| 90° | 0.005 | 0.005 | 0.005 | 0.005 | | |
| 60° | 0.007 | 0.007 | 0.007 | 0.007 | | |
| 30° | 0.012 | 0.012 | 0.012 | 0.012 | | |

Ordering Information Table

| Device Code | | | | | | | |
|---------------|---------------------------|-------------------------|---------------------|---|-------------------------------|--|---|
| | | | | | | | |
| 1 | ST | 100 | 0 | C | 26 | K | 1 |
| 1 | 2 | 3 | 4 | 5 | 6 | 7 | 8 |
| 1 - Thyristor | 2 - Essential part number | 3 - 0 = Converter grade | 4 - C = Ceramic Puk | 5 - Voltage code: Code x 100 = V _{RRM} (See Voltage Ratings Table) | 6 - K = Puk Case A-24 (K-PUK) | 7 - 0 = Eyelet terminals (Gate and Auxiliary Cathode Unsoldered Leads) 1 = Fast-on terminals (Gate and Auxiliary Cathode Unsoldered Leads) 2 = Eyelet terminals (Gate and Auxiliary Cathode Soldered Leads) 3 = Fast-on terminals (Gate and Auxiliary Cathode Soldered Leads) | 8 - Critical dv/dt: None = 500V/μsec (Standard selection) L = 1000V/μsec (Special selection) |

Outline Table

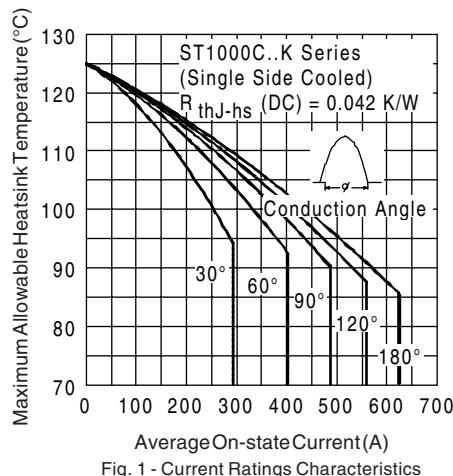
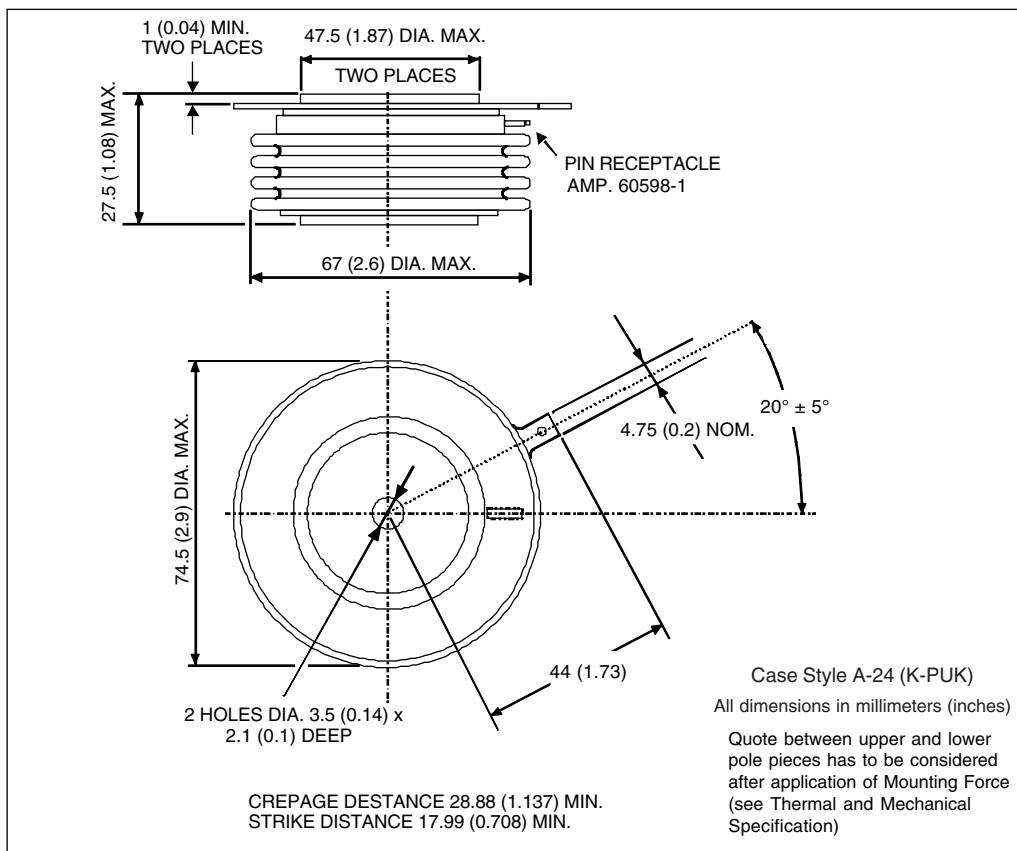


Fig. 1 - Current Ratings Characteristics

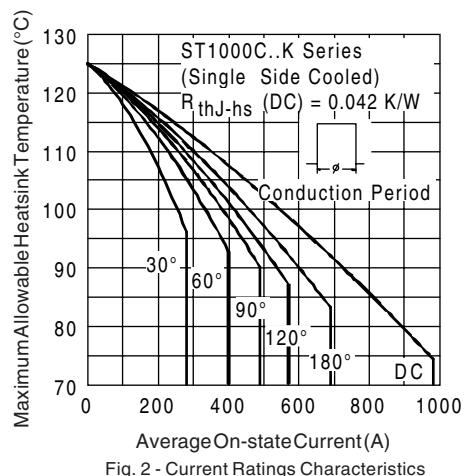


Fig. 2 - Current Ratings Characteristics

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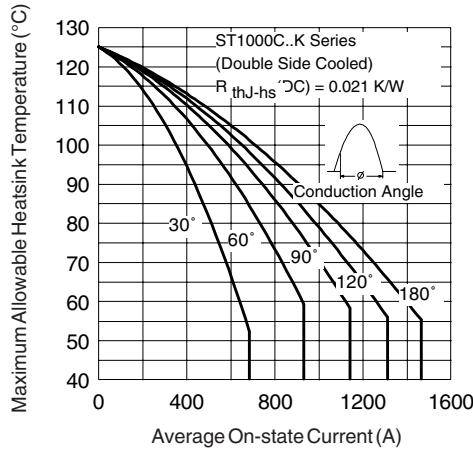


Fig. 3 - Current Ratings Characteristics

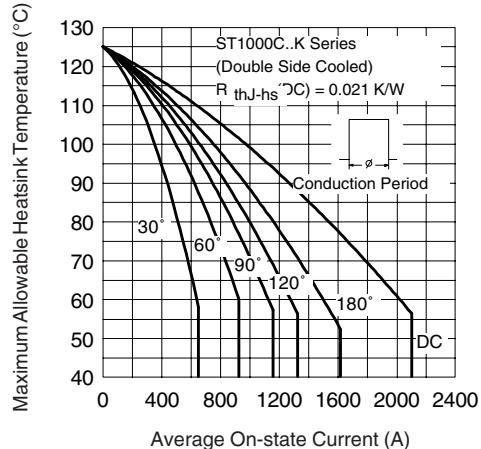


Fig. 4 - Current Ratings Characteristics

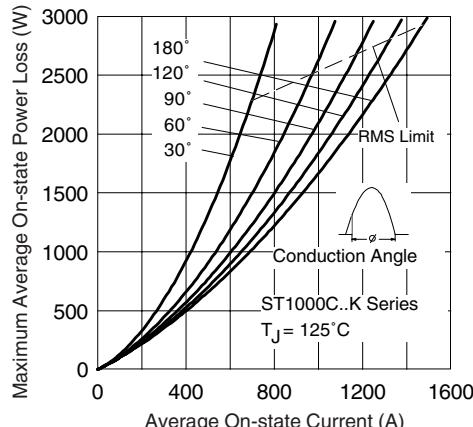


Fig. 5 - On-state Power Loss Characteristics

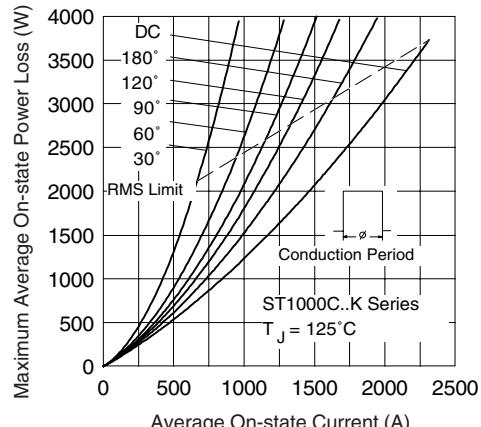


Fig. 6 - On-state Power Loss Characteristics

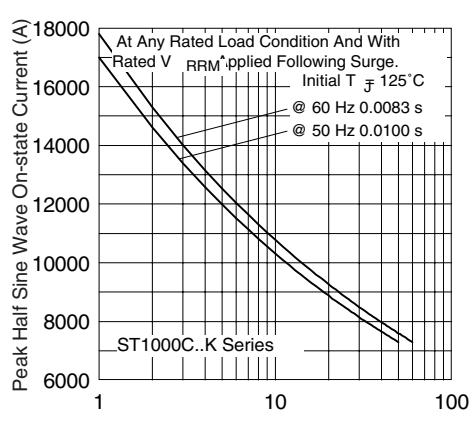


Fig. 7 - Maximum Non-Repetitive Surge Current
Single and Double Side Cooled

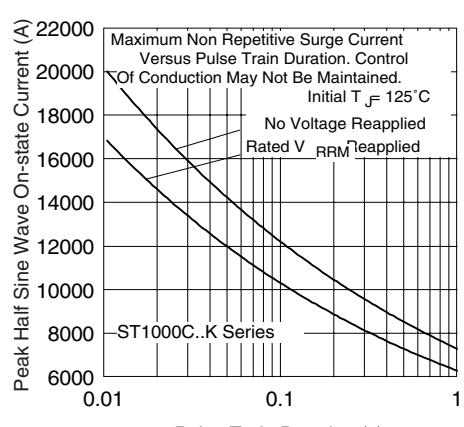


Fig. 8 - Maximum Non-Repetitive Surge Current
Single and Double Side Cooled

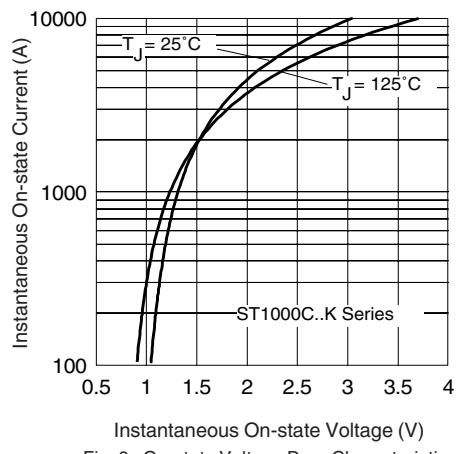


Fig. 9 - On-state Voltage Drop Characteristics

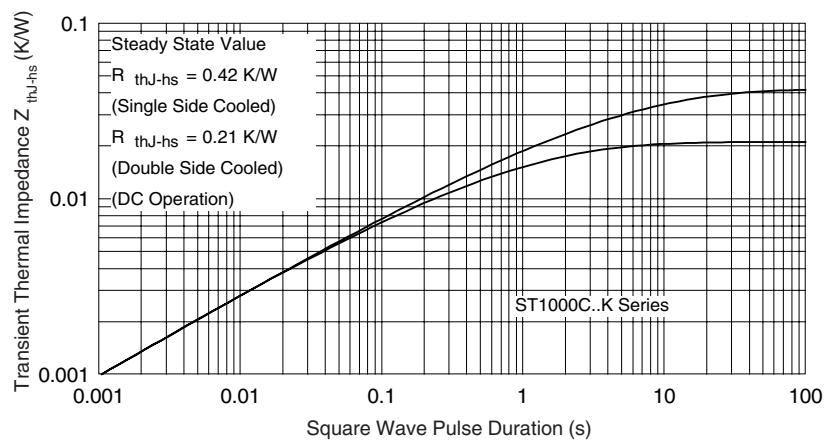


Fig. 10 - Thermal Impedance $Z_{\text{thJ-hs}}$ Characteristics

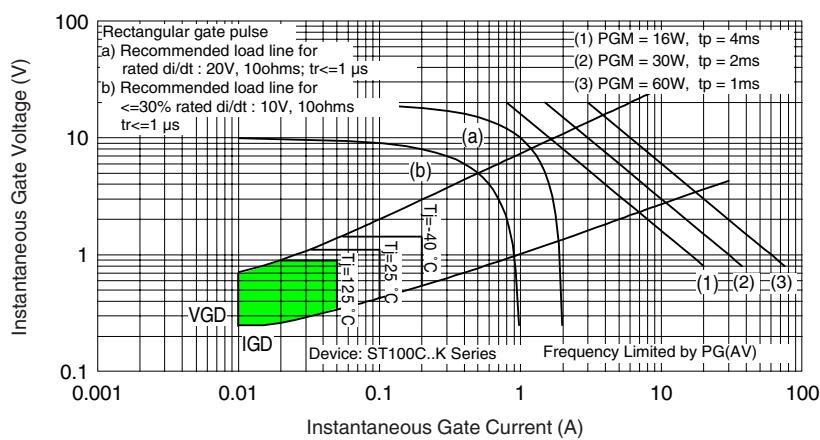


Fig. 11 - Gate Characteristics